

Diego Calvo Ruiz

List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	High-Speed Steep-Slope GaInAs Impact Ionization MOSFETs (I-MOS) With $SS = 1.25 \text{ mV/dec}$ Part II: Dynamic Switching and RF Performance. IEEE Transactions on Electron Devices, 2022, 69, 3549-3556.	1.6	3
2	High-Speed Steep-Slope GaInAs Impact Ionization MOSFETs (I-MOS) With $SS = 1.25 \text{ mV/dec}$ Part I: Material and Device Characterization, DC Performance, and Simulation. IEEE Transactions on Electron Devices, 2022, 69, 3542-3548.	1.6	2
3	Impact of Reduced Gate-to-Source Spacing on Indium Phosphide High Electron Mobility Transistor Performance. Physica Status Solidi (A) Applications and Materials Science, 2021, 218, 2000191.	0.8	2
4	Low-Noise Microwave Performance of 30 nm GaInAs MOS-HEMTs: Comparison to Low-Noise HEMTs. IEEE Electron Device Letters, 2020, 41, 1320-1323.	2.2	6
5	InAs Channel Inset Effects on the DC, RF, and Noise Properties of InP pHEMTs. IEEE Transactions on Electron Devices, 2019, 66, 4685-4691.	1.6	10
6	New GaInAs/InAs/InP Composite Channels for mm-Wave Low-Noise InP HEMTs. , 2019, , .		1
7	Impact Ionization Control in 50 nm Low-Noise High-Speed InP HEMTs with InAs Channel Insets. , 2019, , .		8
8	Effects of Electrochemical Etching on InP HEMT Fabrication. IEEE Transactions on Semiconductor Manufacturing, 2019, 32, 496-501.	1.4	6
9	Evaluation of energy barriers for topological transitions of Si self-interstitial clusters by classical molecular dynamics and the kinetic activation-relaxation technique. , 2017, , .		0
10	Pt Gate Sink-In Process Details Impact on InP HEMT DC and RF Performance. IEEE Transactions on Semiconductor Manufacturing, 2017, 30, 462-467.	1.4	13
11	Novel Vitrified-Bond Ultra-Fine Grinding Technology for SiC Polishing. Materials Science Forum, 0, 1062, 155-159.	0.3	0